

PCN# 20151215003 Die Conversion for Selected LVC LL Devices in the DBV and DCK Packages Change Notification / Sample Request

Date: 12/16/2015 To: TOKYO ELECTRON DEVICE (DSTR) PCN

Dear Customer:

This is an announcement of a change to a device that is currently offered by Texas Instruments. The details of this change are on the following pages.

We request you acknowledge receipt of this notification within **30** days of the date of this notice. Lack of acknowledgement of this notice within 30 days constitutes acceptance of the change. If you require samples or additional data to support your evaluation, please request within 30 days.

The changes discussed within this PCN will not take effect any earlier than **90** days from the date of this notification, unless customer agreement has been reached on an earlier implementation of the change. This notification period is per TI's standard process.

This notice does not change the end-of-life status of any product. Should product affected be on a previously issued product withdrawal/discontinuance notice, this notification does not extend the life of that product or change the life time buy offering/discontinuance plan.

For questions regarding this notice, contact your local Field Sales Representative or the PCN Manager (<u>PCN_ww_admin_team@list.ti.com</u>).

Sincerely,

PCN Team SC Business Services

20151215003 Attachment: 1

Products Affected:

The devices listed on this page are a subset of the complete list of affected devices. According to our records, these are the devices that you have purchased within the past twenty-four (24) months. The corresponding customer part number is also listed, if available.

DEVICE

CUSTOMER PART NUMBER

SN74LVC1G125DCKR	null
SN74LVC1G125DCKT	null
SN74LVC1G126DCKR	null
SN74LVC1G126DCKT	null
SN74LVC1G240DBVR	null
SN74LVC2G06DCKR	null
SN74LVC2G07DBVR	null
SN74LVC2G07DCK3	null
SN74LVC2G07DCKT	null
SN74LVC1G240DCKR	null
SN74LVC2G06DBVR	null
SN74LVC1G126DBVR	null
SN74LVC2G07DCKR	null
SN74LVC1G125DCK3	null
SN74LVC1G11DCKR	null
SN74LVC1G66DCKT	null
SN74LVC1G66DCKR	null
SN74LVC2G17DCKR	null
SN74LVC1G18DCKR	null
SN74LVC1G10DCKR	null
SN74LVC2G17DCKT	null
SN74LVC1G126DBVT	null
SN74LVC1G27DBVR	null
SN74LVC1G332DCKR	null
SN74LVC1G3157DBVR	null

Technical details of this Product Change follow on the next page(s).

PCN Numbe	201	51215003				PCN I	Date: 12	2/16/2015	
Title:	Die Conve	ersion	for Selecte	d LVC LL De	vices in the	DB	V and D	CK Packag	es
Customer C	contact:		PCN Manag	er)ep	t:	Quality Se	rvices
Proposed 1	st Ship Da	te:	3/16/2016		ated Samp ability:	le		Date provi sample ree	•
Change Typ	e:								
Assemb	y Site			y Process				bly Materia	
🛛 Design				Specificatio				nical Specif	ication
Test Site				Shipping/La			Test Pr		
	ump Site			imp Materia				Bump Proc	
🗌 Wafer Fa	ab Site		Wafer Fa	b Materials			Wafer I	Fab Proces	S
				PCN Det	ails				
Description									
This change									
Revision will									
backfill the r									
the product	affected se	ction	of this notif	ication. The	ere will be no	o cł	nange to	the data s	sheet.
Reason for	Change:								
Continuity of	f Supply								
Anticipated	impact o	n Fit,	, Form, Fun	iction, Qua	lity or Relia	abi	lity (po	sitive / n	egative):
Reliability &	electrical c	harac	terization ev	valuation sh	owed no adv	ver	se impao	cts.	
Changes to	product i	denti	ification re	sulting fro	m this PCN	:			
Die Rev desi	gnator will	chan	ge as showr	in the table	e and sampl	e la	ibel belo	ow:	
Current		New	=	1					
Die Rev [2F)]		Rev [2P]						
A/D/E		G		J					
Sample product shipping label to indicate die rev location (not actual product label)									
INSTRUMENTS G4 MADE IN: Malaysia G4 MSL 2 /260C/1 YEAR SEAL DT G3/29/04 OPT: 39 LBL: 5A (L)T0:1750 G4									

Product Affected:	I	I	
74LVC1G10DBVRG4	SN74LVC1G11DBVT	SN74LVC1G27DCKR	SN74LVC2G06DCKR
74LVC1G125DCKRE4	SN74LVC1G11DCKJ	SN74LVC1G27DCKRE4	SN74LVC2G06DCKRE4
74LVC1G125DCKRG4	SN74LVC1G11DCKR	SN74LVC1G27DCKRG4	SN74LVC2G06DCKRG4
74LVC1G125DCKTE4	SN74LVC1G11DCKRE4	SN74LVC1G3157DBV3	SN74LVC2G07DBV3
74LVC1G125DCKTG4	SN74LVC1G11DCKRG4	SN74LVC1G3157DBVR	SN74LVC2G07DBVR
74LVC1G126DBVRE4	SN74LVC1G11DCKR-P	SN74LVC1G3157DBVT	SN74LVC2G07DBVRE4
74LVC1G126DBVRG4	SN74LVC1G11DCKT	SN74LVC1G332DBVR	SN74LVC2G07DBVRG4
74LVC1G126DBVTE4	SN74LVC1G125DCK3	SN74LVC1G332DCKR	SN74LVC2G07DBVT
74LVC1G126DBVTG4	SN74LVC1G125DCK3T	SN74LVC1G332DCKRG4	SN74LVC2G07DCK3
74LVC1G126DCKRE4	SN74LVC1G125DCK6	SN74LVC1G386DBVR	SN74LVC2G07DCKJ
74LVC1G126DCKRG4	SN74LVC1G125DCKJ	SN74LVC1G386DCKR	SN74LVC2G07DCKR
74LVC1G126DCKTG4	SN74LVC1G125DCKR	SN74LVC1G66DBVR	SN74LVC2G07DCKRE4
74LVC1G240DBVRE4	SN74LVC1G125DCKR-P	SN74LVC1G66DBVRE4	SN74LVC2G07DCKRG4
74LVC1G240DBVRG4	SN74LVC1G125DCKT	SN74LVC1G66DBVRG4	SN74LVC2G07DCKR-P
74LVC1G240DBVTG4	SN74LVC1G126DBVR	SN74LVC1G66DBVT	SN74LVC2G07DCKR-P3
74LVC1G240DCKRE4	SN74LVC1G126DBVT	SN74LVC1G66DBVTG4	SN74LVC2G07DCKT
74LVC1G240DCKRG4	SN74LVC1G126DCKJ	SN74LVC1G66DCK3	SN74LVC2G07DCKTG4
74LVC1G240DCKTG4	SN74LVC1G126DCKR	SN74LVC1G66DCK3T	SN74LVC2G17DBV3
74LVC1G3157DBVRE4	SN74LVC1G126DCKR-P	SN74LVC1G66DCKJ	SN74LVC2G17DBVR
74LVC1G3157DBVRG4	SN74LVC1G126DCKT	SN74LVC1G66DCKR	SN74LVC2G17DBVRE4
74LVC1G332DBVRG4	SN74LVC1G18DBV3	SN74LVC1G66DCKRE4	SN74LVC2G17DBVRG4
74LVC1G332DCKRE4	SN74LVC1G18DBVR	SN74LVC1G66DCKRG4	SN74LVC2G17DBVR-P
74LVC1G386DCKRG4	SN74LVC1G18DBVRG4	SN74LVC1G66DCKR-P	SN74LVC2G17DBVT
SN74LVC1G10DBVR	SN74LVC1G18DCKR	SN74LVC1G66DCKT	SN74LVC2G17DBVTG4
SN74LVC1G10DBVT	SN74LVC1G18DCKRE4	SN74LVC1G66DCKTG4	SN74LVC2G17DCK3
SN74LVC1G10DCKJ	SN74LVC1G18DCKRG4	SN74LVC1G97DCK3T	SN74LVC2G17DCKJ
SN74LVC1G10DCKR	SN74LVC1G240DBVR	SN74LVC1G97DCKJ	SN74LVC2G17DCKR
SN74LVC1G10DCKRG4	SN74LVC1G240DBVT	SN74LVC1G97DCKR-NG	SN74LVC2G17DCKRE4
SN74LVC1G10DCKT	SN74LVC1G240DCK3T	SN74LVC1G97DCKR-P	SN74LVC2G17DCKRG4
SN74LVC1G11DBVR	SN74LVC1G240DCKR	SN74LVC2G06DBV3	SN74LVC2G17DCKR-P
SN74LVC1G11DBVRE4	SN74LVC1G240DCKT	SN74LVC2G06DBVR	SN74LVC2G17DCKT
SN74LVC1G11DBVRG4	SN74LVC1G27DBVR	SN74LVC2G06DBVRE4	SN74LVC2G17DCKTE4
SN74LVC1G11DBVR-P	SN74LVC1G27DBVRE4	SN74LVC2G06DBVRG4	SN74LVC2G17DCKTG4
SN74LVC1G11DBVR-P3	SN74LVC1G27DBVRG4	SN74LVC2G06DCKJ	

Qualification Data: DCK Devices (Approved 8/04/2011)						
This qualification has been specifically developed for the validation of this change. The qualification data validates that the proposed change meets the applicable released technical specifications.						
		-				
	Qualification Device Cons					
	Qualification Vehicle #1: S	N74LVC1G00D	CKR			
Wafer Fab Site:	FFAB	Wafer Process:	50b10.13_BOPO2 / P9792			
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000/T	Wafer Size Dia.	200mm			

	iN500				
Qualification:	Plan 🛛 Test Results		1		
Reliability Test	Conditions		San	nple Size(PASS/FAIL)	
Manufacturability-TQ	Assembly (per mfg. Site s	specification)		PASS	
X-Ray	Approved by A-T Site			PASS	
Notes: Qualifi	cation tests "pass" on zero fa	ils for each test			
	Qualification Vehicle #2:	SN74LVC1G02D	CKR		
Wafer Fab Site:	FFAB	Wafer Process:	50b1	10.13_BOPO2 / P9792	
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200n	nm	
Qualification:	Plan 🛛 Test Results				
Reliability Test	Conditions		Sai	mple Size(PASS/FAIL)	
Electrical Char -LV	Approved by Product Eng	ineer		PASS	
Manufacturability-TQ	Approved by A-T Site			PASS	
Notes: Qualifi	cation tests "pass" on zero fa	ils for each test			
	Qualification Vehicle #3:	SN74LVC1G04D	CKR		
Wafer Fab Site:	FFAB	Wafer Process:	50b1	10.13_BOPO2 / P9792	
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200n	nm	
Qualification:	Plan 🛛 Test Results				
Reliability Test	Conditions	0	Sampl	e Size (PASS/FAIL)	
Manufacturability-TQ	Approved by A-T Site			PASS	
Notes: Qualifi	cation tests "pass" on zero fa	ils for each test			
	Qualification Vehicle #4:	SN74LVC1G06D	CKR		
Wafer Fab Site:	FFAB	Wafer Process:	50b1	10.13_BOPO2 / P9792	
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200n	าฑ	
Qualification:	Plan 🛛 Test Results				
Reliability Test	Conditions		Sample Size (PASS/FAIL)		
Electrical Char - LV	Approved by Product Eng	ineer	PASS		
Manufacturability-TQ	Approved by A-T Site			PASS	
	cation tests "pass" on zero fa	ils for each test			
	Qualification Vehicle #5:	SN74LVC1G07D	CKR		
Wafer Fab Site:	FFAB	Wafer Process:	50b1	10.13_BOPO2 / P9792	
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200n	nm	
Qualification: 🗌 Plan 🛛 Test Results					
Reliability Test Conditions				Sample Size (PASS/FAIL)	
Electrical Char - LV Approved by Product Engineer				PASS	
Manufacturability-TQ Approved by A-T Site				PASS	
Notes: Qualification tests "pass" on zero fails for each test					
Qualification Vehicle #6: SN74LVC1G08DCKR					
Wafer Fab Site:	FFAB	Wafer Process:			
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000	Wafer Size Dia.	200mm		

	/TiN500				
Qualification:	Plan 🛛 Test Results				
Reliability Test	Conditions			Sample Size (PASS/FAIL)	
Electrical Char - LV	Approved by Product Eng	ineer		PASS	
Manufacturability-TQ	Approved by A-T Site			PASS	
Notes: Qualifi	cation tests "pass" on zero fai Qualification Vehicle #7:		סער		
Wafer Fab Site:	FFAB	Wafer Process:	50b1	L0.13_BOPO2 / P9792	
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200n	าท	
Qualification:	Plan 🛛 Test Results				
Reliability Test	Conditions			Sample Size (PASS/FAIL)	
Electrical Char - LV	Approved by Product Eng	ineer		PASS	
Manufacturability-TQ	Approved by A-T Site			PASS	
Notes: Qualifi	cation tests "pass" on zero fai Qualification Vehicle #8:		סער		
Wafer Fab Site:	FFAB	Wafer Process:		L0.13_BOPO2 / P9792	
	FFAD	Waler Process.	300.	10.13_DOPO2 / P9792	
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200n	าฑ	
Qualification:	Plan 🛛 Test Results				
Reliability Test	Conditions			Sample Size (PASS/FAIL)	
Electrical Char - LV	Approved by Product Eng	ineer	r PASS		
Manufacturability-TQ	Approved by A-T Site	PASS			
Notes: Qualifi	cation tests "pass" on zero fai Qualification Vehicle #9:	ils for each test			
Wafer Fab Site:	FFAB	Wafer Process:	50b1	10.13_BOPO2 / P9792	
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200n	าฑ	
Qualification:	Plan 🛛 Test Results				
Reliability Test	Conditions			Sample Size (PASS/FAIL)	
Electrical Char - LV	Approved by Product Eng	ineer		PASS	
Manufacturability-TQ	Approved by A-T Site			PASS	
	cation tests "pass" on zero fai				
	Qualification Vehicle #10:				
Wafer Fab Site:	FFAB	Wafer Process:	50b1	L0.13_BOPO2 / P9792	
Protective Die Coating: Ti300/TiN1700/AlCu0.5=6000 /TiN500 Wafer Size Dia. 200mm				าฑ	
Qualification: 🗌 Plan 🛛 Test Results					
Reliability Test			Sample Size (PASS/FAIL)		
Electrical Char - LV	ineer		PASS		
Manufacturability-TQ	Approved by A-T Site			PASS	
Notes: Qualifie	cation tests "pass" on zero fa	ils for each test			

Qualification Vehicle #11: SN74LVC1G38DCKR					
Wafer Fab Site:	FFAB	FAB Wafer Process: 50t		50b10.13_BOPO2 / P9792	
Protective Die Coating:	Protective Die Coating: Ti300/TiN1700/AlCu0.5=6000 /TiN500 Wafer Size Dia. 200r			nm	
Qualification: P	an 🛛 Test Results				
Reliability Test			Sample Size (PASS/FAIL)		
Electrical Char - LV	Approved by Product Engi	neer		PASS	
Manufacturability-TQ	Approved by A-T Site		PASS		
Notes: Qualific	ation tests "pass" on zero fai	ls for each test			
Q	ualification Vehicle #12:	SN74LVC1GU04	DCKF	2	
Wafer Fab Site:	FFAB	Wafer Process:	50b10.13_BOPO2 / P9792		
Protective Die Coating:	Protective Die Coating: Ti300/TiN1700/AlCu0.5=6000 Wafer Size Dia. 200			200mm	
Qualification: P	an 🛛 Test Results				
Reliability Test Conditions				Sample Size (PASS/FAIL)	
Electrical Char - LV Approved by Product En		lineer		PASS	
Manufacturability-TQ	PASS				
Notes: Qualific					

Qualifica	Qualification Data: DBV Devices (Approved 8/22/2011)				
This qualification has b	peen specifically developed for	r the validation of	this c	hange. The	
	ates that the proposed chang	e meets the applic	able	released technical	
specifications.					
	Qualification Device Con				
	Qualification Vehicle #1:	SN74LVC1G00D	BVR		
Wafer Fab Site:	FFAB	Wafer Process:	50b:	10.13_BOPO2 / P9792	
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6 000/TiN500	Wafer Size Dia.	200	nm	
Qualification:	Plan 🛛 Test Results				
Reliability Test	Conditions			Sample Size (PASS/FAIL)	
Electrical Char	Approved by Product Engi	neer		PASS	
Manufacturability-TQ	Assembly (per mfg. Site s			PASS	
ESD CDM	1500V			3/0	
X-Ray	Approved by A-T Site; Bo	ttom side Only		5/0	
Notes: Qualifi	cation tests "pass" on zero fai				
	Qualification Vehicle #2:	SN74LVC1G02D	BVR		
Wafer Fab Site:	te: FFAB Wafer Process: 50b10.13_BOPO2 / P979			10.13_BOPO2 / P9792	
Protective Die Ti300/TiN1700/AlCu0.5=6 Wafer Size Dia. 200mr Coating: 000/TiN500			nm		
Qualification:	lan 🛛 Test Results				
Reliability Test	Conditions			Sample Size (PASS/FAIL)	
Electrical Char	Approved by Product Engi	neer		PASS	
Manufacturability-TQ	Assembly (per mfg. Site s	pecification)		PASS	
ESD CDM	1500V	•		3/0	
Notes: Qualifi	cation tests "pass" on zero fai	ls for each test			
	Qualification Vehicle #3:	SN74LVC1G04D	BVR		
Wafer Fab Site:	FFAB	Wafer Process:	50b:	10.13_BOPO2 / P9792	
Protective Die Ti300/TiN1700/AlCu0.5=6 Wafer Size Dia. 200 Coating: 000/TiN500			200	nm	
Qualification: 🗌 Plan 🛛 Test Results					
Reliability Test Conditions			Sample Size (PASS/FAIL)		
Electrical Char	Approved by Product Engi	t Engineer		PASS	
Manufacturability-TQ Assembly (per mfg. Site specifica				PASS	
ESD CDM 1500V 3/0					
Notes: Qualifi	cation tests "pass" on zero fai	ls for each test			

	Qualification Vehicle #4:	SN74LVC1G06D	BVR	
Wafer Fab Site:	FFAB	Wafer Process:		10.13 BOPO2 / P9792
Protective Die	Ti300/TiN1700/AlCu0.5=6 000/TiN500	Wafer Size Dia.	200	nm
Coating:				
Qualification:	Plan 🛛 Test Results			Comunita Cina
Reliability Test	Conditions			Sample Size (PASS/FAIL)
Electrical Char -LV	Approved by Product Eng	ineer		PASS
Manufacturability-TQ	Assembly (per mfg. Site s	specification)		PASS
ESD CDM	1500V			3/0
Notes: Qualifi	cation tests "pass" on zero fai			
	Qualification Vehicle #5:	SN74LVC1G07D	BVR	
Wafer Fab Site:	FFAB	Wafer Process:	50b:	10.13_BOPO2 / P9792
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6 000/TiN500	Wafer Size Dia.	2001	nm
Qualification:	Plan 🛛 Test Results			
Reliability Test	Conditions			Sample Size (PASS/FAIL)
Electrical Char -LV	Approved by Product Eng	ineer		PASS
Manufacturability-TQ	Assembly (per mfg. Site s	specification)		PASS
ESD CDM	1500V	•		3/0
Notes: Qualifi	cation tests "pass" on zero fai			
	Qualification Vehicle #6:	SN74LVC1G08D	BVR	
Wafer Fab Site:	FFAB	Wafer Process:	50b:	10.13_BOPO2 / P9792
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6 000/TiN500	Wafer Size Dia.	2001	nm
Qualification:	Plan 🛛 Test Results			
Reliability Test	Conditions			Sample Size (PASS/FAIL)
Electrical Char -LV	Approved by Product Eng	neer		PASS
Manufacturability-TQ	Assembly (per mfg. Site s			PASS
ESD CDM	1500V	•		3/0
Notes: Qualifi	cation tests "pass" on zero fai			
	Qualification Vehicle #7:	SN74LVC1G14D	BVR	
Wafer Fab Site:	FFAB	Wafer Process:	50b	10.13_BOPO2 / P9792
Protective Die Ti300/TiN1700/AlCu0.5=6 Wafer Size Dia. 2 Coating: 000/TiN500			2001	nm
Qualification: Plan I Test Results				
Reliability Test			Sample Size (PASS/FAIL)	
Electrical Char -LV Approved by Product Engineer				PASS
Manufacturability-TQ Assembly (per mfg. Site specifica				PASS
ESD CDM	1500V			3/0
Notes: Qualification tests "pass" on zero fails for each test				

	Qualification Vehicle #8:	SN74LVC1G17D	BVR			
Wafer Fab Site:	FFAB	Wafer Process:		10.13 BOPO2 / P9792		
			505.			
Protective Die	Ti300/TiN1700/AlCu0.5=6	Wafer Size Dia.	200	mm		
Coating:	000/TiN500					
Qualification:						
Reliability Test	Conditions			Sample Size		
Electrical Char -LV	Approved by Product Eng	ineer		(PASS/FAIL) PASS		
Manufacturability-TQ	Assembly (per mfg. Site s			PASS		
ESD CDM	1500V	specification		3/0		
	cation tests "pass" on zero fa	ils for each test		5/0		
,,,,,, ,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	Qualification Vehicle #9:		BVR			
Wafer Fab Site:	FFAB	Wafer Process:	50b:	10.13_BOPO2 / P9792		
	T:200/T:NI4 700/ALC 0.5					
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6 000/TiN500	Wafer Size Dia.	2001	nm		
	Plan 🛛 Test Results					
				Sample Size		
Reliability Test	Conditions			(PASS/FAIL)		
Electrical Char -LV	Approved by Product Eng	ineer		PASS		
Manufacturability-TQ	Assembly (per mfg. Site s	specification)		PASS		
ESD CDM	1500V			3/0		
Notes: Qualifi	cation tests "pass" on zero fa					
	Qualification Vehicle #10:	SN74LVC1G34D	DBVR			
Wafer Fab Site:	FFAB	Wafer Process:	50b:	10.13_BOPO2 / P9792		
Protective Die	Ti300/TiN1700/AlCu0.5=6					
Coating:	000/TiN500	Wafer Size Dia.	2001	nm		
Qualification:	Plan 🛛 Test Results		1			
				Sample Size		
Reliability Test	Conditions		(PASS/FAIL)			
Electrical Char -LV	Approved by Product Eng			PASS		
Manufacturability-TQ	Assembly (per mfg. Site s	specification)		PASS		
ESD CDM	1500V			3/0		
Notes: Qualifi	cation tests "pass" on zero fa					
	Qualification Vehicle #11:	SN74LVC1G38D	DBVR			
Wafer Fab Site:	FFAB	Wafer Process:	50b:	10.13_BOPO2 / P9792		
Protective Die	Ti300/TiN1700/AlCu0.5=6		_			
Coating: 000/TiN500 Wafer Size Dia. 200			2001	nm		
Qualification: Plan Test Results						
Reliability Test Conditions				Sample Size (PASS/FAIL)		
Electrical Char -LV Approved by Product Engineer			PASS			
Manufacturability-TQ Assembly (per mfg. Site specification)			PASS			
ESD CDM	1500V			3/0		
Notes: Qualification tests "pass" on zero fails for each test						

Qualification Vehicle #12: SN74LVC1GU04DBVR						
Wafer Fab Site:	FFAB	Wafer Process:	50b:	10.13_BOPO2 / P9792		
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6 000/TiN500	Wafer Size Dia.	200mm			
Qualification: 🗌 Plan 🛛 Test Results						
Reliability Test	Conditions			Sample Size (PASS/FAIL)		
Electrical Char -LV	Approved by Product Engi	ineer		PASS		
Manufacturability-TQ Assembly (per mfg. Site specification)				PASS		
ESD CDM	1500V			3/0		
Notes: Qualification tests "pass" on zero fails for each test						

Reference Qualification: LVC Little Logic Devices in 6 Pin DSF 1G00/1G02/1G08/1G32/1G38 - HNT

Qualification Data: DSF Devices (Approved 3/30/2011)

This qualification has been specifically developed for the validation of this change. The qualification data validates that the proposed change meets the applicable released technical specifications.

Qualification Device Construction Details:							
	Qualification Vehicle #1: SN74LVC1G00DSFR						
Wafer Fab Site: FFAB		Wafer Process:	50b1	.0.13_BOPO2 / P9792			
Protective Die Coating:	Wafer Size Dia.	200mm					
Qualification:	lan 🛛 Test Results						
Reliability Test Conditions				Sample Size (PASS/FAIL)			
Electrical Char	Approved by Product Engi	proved by Product Engineer					
Manufacturability-TQ	Assembly (per mfg. Site specification)			PASS			
ESD CDM	1500V			3/0			
X-Ray	Approved by A-T Site; Bottomside Only			5/0			
ESD MM	250V			3/0			
ESD HBM	3500V			3/0			
Latch Up	JESD 78, Class II	JESD 78, Class II					
Steady State Life Test	150C, 300 Hrs	150C, 300 Hrs					
Manufacturability (assy)				Pass			
Notes: Qualific	cation tests "pass" on zero fai	ls for each test					

Qualification Vehicle #2: SN74LVC1G02DSFR					
Wafer Fab Site:	FFAB	Wafer Process:	50b10.13_BOPO2 / P9792		
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm		
Qualification: P	lan 🛛 Test Results				
Reliability Test	Conditions	ions		Sample Size (PASS/FAIL)	
Electrical Char	Approved by Product Engi	neer		PASS	
Manufacturability-TQ	Assembly (per mfg. Site s	pecification)		PASS	
ESD CDM	1500V	· · · ·		3/0	
Latch-Up	JESD 78, Class II			6/0	
ESD MM	200V			3/0	
ESD HBM	4000V			3/0	
Notes: Qualifie	cation tests "pass" on zero fail	ls for each test			
	Qualification Vehicle #3:	SN74LVC1G08D	SFR		
Wafer Fab Site:	FFAB	Wafer Process:	50b1	.0.13_BOPO2 / P9792	
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm		
Qualification:	lan 🛛 Test Results				
Reliability Test	Conditions			Sample Size (PASS/FAIL)	
Electrical Char	Electrical Char Approved by Product Engineer		PASS		
Manufacturability-TQ		Assembly (per mfg. Site specification)		PASS	
ESD CDM	1500V	· · · ·		3/0	
ESD MM	200V			3/0	
Latch Up JESD 78, Class II				6/0	
ESD HBM 4000V				3/0	
Notes: Qualific	cation tests "pass" on zero fail	ls for each test			
	Qualification Vehicle #4: SN74LVC1G32DSFR				
Wafer Fab Site:	FFAB	Wafer Process:	50b10.13_BOPO2 / P9792		
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm		
Qualification: 🗌 Plan 🛛 Test Results					
Reliability Test Conditions			Sample Size (PASS/FAIL)		
Electrical Char	Approved by Product Engineer			PASS	
Manufacturability-TQ Assembly (per mfg. Site specification)				PASS	
ESD CDM				3/0	
ESD MM				3/0	
ESD HBM				3/0	
Latch Up	JESD 78, Class II	JESD 78, Class II		6/0	
Notes: Qualification tests "pass" on zero fails for each test					

Qualification Vehicle #5: SN74LVC1G38DSFR				
Wafer Fab Site:	FFAB	Wafer Process:	50b10.13_BOPO2 / P9792	
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm	
Qualification: P	lan 🛛 Test Results			
Reliability Test Conditions				Sample Size (PASS/FAIL)
Electrical Char	Electrical Char Approved by Product Engineer			PASS
Manufacturability-TQ Assembly (per mfg. Site spec		pecification)		PASS
ESD CDM	ESD CDM 1500V			3/0
Latch-Up JESD 78, Class II				6/0
ESD MM 200V				3/0
ESD HBM 4000V				3/0
Notes: Qualification tests "pass" on zero fails for each test				

Reference Qualification: LVC Little Logic Devices in 6 Pin DSF 1G04/1G06/1G07/1G14/1G17/1G34/1GU04 - HNT

Qualification Data: DSF Devices (Approved 6/27/2011) This qualification has been specifically developed for the validation of this change. The qualification data validates that the proposed change meets the applicable released technical specifications.

Qualification Device Construction Details:				
Qualification Vehicle #1: SN74LVC1G04DSFR				
Wafer Fab Site:	FFAB	Wafer Process:	50b10.13_BOPO2 / P9792	
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm	
Qualification: P	lan 🛛 Test Results			
Reliability Test	Conditions			Sample Size (PASS/FAIL)
Electrical Char	Approved by Product Engi	ed by Product Engineer		PASS
Manufacturability-TQ	Assembly (per mfg. Site s	bly (per mfg. Site specification)		PASS
ESD CDM	1500V			3/0
X-Ray Approved by A-T Site; Botto		ttomside Only		5/0
ESD MM	250V			3/0
ESD HBM	5000V			3/0
Latch Up JESD 78, Class II				6/0
Steady State Life Test	150C, 300 Hrs	5		77/0
Notes: Qualification tests "pass" on zero fails for each test				

Qualification Vehicle #2: SN74LVC1G06DSFR					
Wafer Fab Site:	FFAB	Wafer Process:	50b10.13_BOPO2 / P9792		
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm		
Qualification:	Plan 🛛 Test Results		1		
Reliability Test	Conditions		Sample Size (PASS/FAIL)		
Electrical Char	Approved by Product Engi	neer		PASS	
Manufacturability-TQ	Assembly (per mfg. Site s			PASS	
ESD CDM	1500V	,		3/0	
Latch-Up	JESD 78, Class II			6/0	
ESD MM	200V			3/0	
ESD HBM	3500V			3/0	
	cation tests "pass" on zero fail	ls for each test		, -	
	Qualification Vehicle #3:		SFR		
Wafer Fab Site:	FFAB	Wafer Process:	50b1	.0.13_BOPO2 / P9792	
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm		
Qualification:	Plan 🛛 Test Results				
Reliability Test	Reliability Test Conditions			Sample Size (PASS/FAIL)	
Electrical Char	Electrical Char Approved by Product Engineer		PASS		
Manufacturability-TQ		ssembly (per mfg. Site specification)		PASS	
ESD CDM			3/0		
ESD MM	250V			3/0	
Latch Up	JESD 78, Class II		6/0		
ESD HBM	4000V			3/0	
Notes: Qualifie	cation tests "pass" on zero fail	ls for each test			
	Qualification Vehicle #4: SN74LVC1G14DSFR				
Wafer Fab Site:	FFAB	Wafer Process:			
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm		
Qualification: Plan 🛛 Test Results					
Reliability Test Conditions			Sample Size (PASS/FAIL)		
Electrical Char	Approved by Product Engi	roduct Engineer		PASS	
Manufacturability-TQ				PASS	
ESD CDM				3/0	
ESD MM				3/0	
ESD HBM	4000V			3/0	
Latch Up	JESD 78, Class II			6/0	
Notes: Qualification tests "pass" on zero fails for each test					

Qualification Vehicle #5: SN74LVC1G17DSFR					
Wafer Fab Site:	FFAB	Wafer Process:	50b10.13_BOPO2 / P9792		
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm		
Qualification: P	lan 🛛 Test Results				
Reliability Test	Conditions		Sample Size (PASS/FAIL)		
Electrical Char	Approved by Product Engi	neer		PASS	
Manufacturability-TQ	Assembly (per mfg. Site s	pecification)		PASS	
ESD CDM	1500V			3/0	
Latch-Up	JESD 78, Class II			6/0	
ESD MM	250V			3/0	
ESD HBM	2000V			3/0	
Notes: Qualific	cation tests "pass" on zero fail	ls for each test			
	Qualification Vehicle #6:	SN74LVC1G34D	SFR		
Wafer Fab Site:	FFAB	Wafer Process:	50b1	.0.13_BOPO2 / P9792	
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm		
Qualification:	lan 🛛 Test Results				
Reliability Test			Sample Size (PASS/FAIL)		
Electrical Char Approved by Product Engineer		PASS			
Manufacturability-TQ		hbly (per mfg. Site specification)		PASS	
ESD CDM 1500V			3/0		
ESD MM				3/0	
ESD HBM	4000V			3/0	
Latch Up	JESD 78, Class II			6/0	
	cation tests "pass" on zero fail	ls for each test		· ·	
-	Qualification Vehicle #7:		SFR		
Wafer Fab Site:	FFAB	Wafer Process:	50b10.13_BOPO2 / P9792		
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm		
Qualification: Dan I Test Results					
Reliability Test Conditions			Sample Size (PASS/FAIL)		
Electrical Char	Approved by Product Engineer			PASS	
Manufacturability-TQ	· · · · · · · · · · · · · · · ·	nbly (per mfg. Site specification)		PASS	
ESD CDM 1500V				3/0	
Latch-Up JESD 78, Class II				6/0	
ESD MM	250V			3/0	
ESD HBM	2000V			3/0	
	cation tests "pass" on zero fail	ls for each test			

Reference Qualification: FFAB BOPO2 flows 25b10, 33b10 and 50b10

Qualification Data: Approved 12/11/2008 This qualification has been specifically developed for the validation of this change. The qualification data validates that the proposed change meets the applicable released technical specifications.

valuates that the proposed change meets the applicable released technical specifications.					
Qual De	vice 1: SN74AUC1G	08DCK (MSL 1-2	600	C)	
Wafer Fab Sit	e: FFAB	Wafer Process:		25B10/_BOPO2 / D9672	
Protective Die Coatin	g: 10KCN	Wafer Size Dia.		200mm	
Qualification: 🗌 Plan	Test Results				
Reliability Test	Conditions/Durations	on	Sample Size / Fail		
**Steady State Life Test (HTOL)	150C, 300 Hrs			116/0	
**Biased HAST	130C/85%RH/96 Hrs			77/0	
**T/C -65C/150C	-65C/+150C (1000 Cy	c)		77/0	
**Autoclave 121C	121C, 15 PSI (96 Hrs)			77/0	
Manufacturability	(per mfg. Site specifica	ition)		Pass	
Electrical Char				Pass	
ESD HBM	2500V			3/0	
ESD MM	250V			3/0	
ESD CDM				3/0	
Latch-Up	JESD 78, Class II		6/0		
** Preconditioning sequence: leve	l 1-260C				
Qual Dev	vice 2: SN74AVC8T2	45PW (MSL 1-2	600	2)	
Wafer Fab Sit	e: FFAB	Wafer Process:		33B10 /_BOPO2 / D9722	
Protective Die Coatin	g: 10KCN	Wafer Size Dia.		200mm	
Qualification: 🗌 Plan 🛛 Test Results					
Reliability Test	Conditions/Durati	on	Sample Size / Fail		
**Steady State Life Test (HTOL)	150C, 300 Hrs		116/0		
**Biased HAST	130C/85%RH/96 Hrs 77/0		77/0		
**T/C -65C/150C	-65C/+150C (1000 Cyc) 76/0		76/0		
**Autoclave 121C	121C, 15 PSI (96 Hrs) 77/0		77/0		
Manufacturability	(per mfg. Site specification) Pass		Pass		
Electrical Char			Pass		
ESD HBM	8000V		3/0		
ESD MM	250V		3/0		
ESD CDM	2000V		3/0		
Latch-Up JESD 78, Class II 6/0		6/0			
** Preconditioning sequence: leve	l 1-260C				

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

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